TOSHIBA Diode Silicon Epitaxial Planar Type

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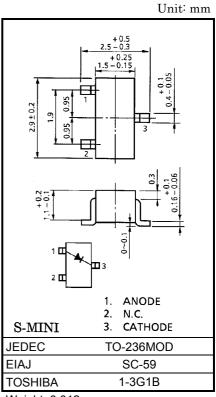
Ultra High Speed Switching Application

• Small package : SC-59

• Low forward voltage : V_{F} (3) = 0.9V (typ.) • Fast reverse recovery time: t_{rr} = 1.6ns (typ.) • Small total capacitance : C_{T} = 0.9pF (typ.)

Maximum Ratings (Ta = 25°C)

| Characteristic | Symbol | Rating | Unit |
|--------------------------------|------------------|-----------------|------|
| Maximum (peak) reverse voltage | V_{RM} | 85 | V |
| Reverse voltage | V _R | 80 | V |
| Maximum (peak) forward current | I _{FM} | 300 | mA |
| Average forward current | IO | 100 | mA |
| Surge current (10ms) | I _{FSM} | 2 | Α |
| Power dissipation | Р | 150 | mW |
| Junction temperature | Tj | 125 | °C |
| Storage temperature range | T _{stg} | − 55~125 | °C |



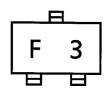
Weight: 0.012g

Electrical Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Circuit | Test Condition | Min | Тур. | Max | Unit | |
|-----------------------|--------------------|-----------------|--|-----|------|------|------|--|
| Forward voltage | V _{F (1)} | _ | I _F =1mA | _ | 0.60 | - | | |
| | V _{F (2)} | _ | I _F = 10mA | _ | 0.72 | _ | ٧ | |
| | V _{F (3)} | _ | I _F = 100mA | _ | 0.90 | 1.20 | | |
| Reverse current | I _{R (1)} | _ | V _R = 30V | _ | _ | 0.1 | | |
| | I _{R (2)} | _ | V _R = 80V | _ | _ | 0.5 | μА | |
| Total capacitance | C _T | _ | V _R = 0, f = 1MH _z | _ | 0.9 | 3.0 | pF | |
| Reverse recovery time | t _{rr} | _ | I _F = 10mA (Fig.1) | _ | 1.6 | 4.0 | ns | |

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Marking



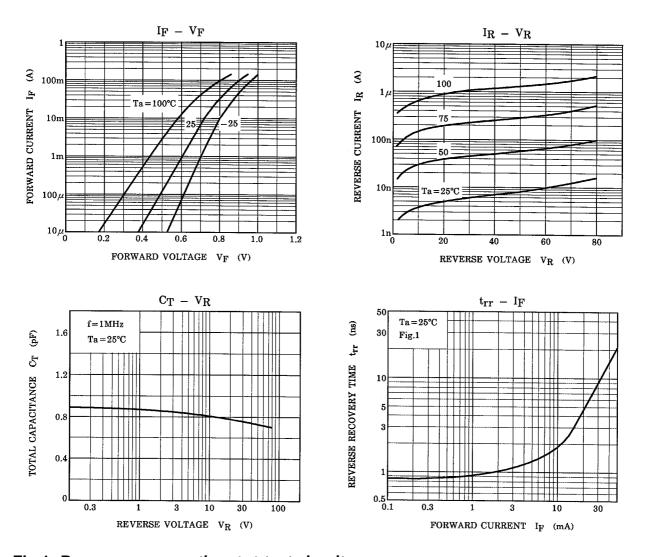
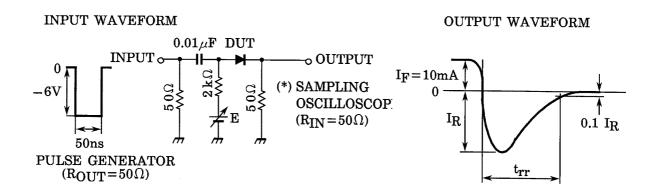


Fig.1 Reverse recovery time (t_{rr}) test circuit



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